

ST180C..C SERIES

PHASE CONTROL THYRISTORS

Hockey Puk Version

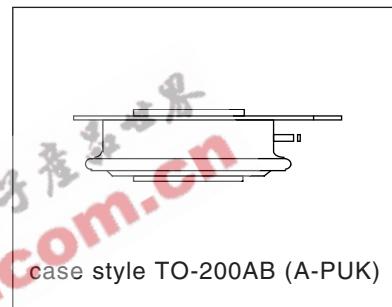
Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AB (A-PUK)

350A

Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers



Major Ratings and Characteristics

Parameters	ST180C..C	Units
$I_{T(AV)}$	350	A
@ T_{hs}	55	°C
$I_{T(RMS)}$	660	A
@ T_{hs}	25	°C
I_{TSM}	5000	A
@ 60Hz	5230	A
I^2t	125	KA ² s
@ 60Hz	114	KA ² s
V_{DRM}/V_{RRM}	400 to 2000	V
t_q typical	100	μs
T_J	- 40 to 125	°C

ST180C..C Series

Bulletin I25164 rev. C 02/00

International
IR Rectifier

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{DRM}/V_{RRM} , max. repetitive peak and off-state voltage V	V_{RSM} , maximum non-repetitive peak voltage V	I_{DRM}/I_{RRM} max. @ $T_J = T_{J\max}$ mA
ST180C..C	04	400	500	30
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	18	1800	1900	
	20	2000	2100	

On-state Conduction

Parameter	ST180C..C	Units	Conditions
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	350 (140)	A	180° conduction, half sine wave double side (single side) cooled
	55 (85)	°C	
$I_{T(RMS)}$ Max. RMS on-state current	660	A	@ 25°C heatsink temperature double side cooled
I_{TSM} Max. peak, one-cycle non-repetitive surge current	5000		
	5230		
	4200		
	4400		
I^2t Maximum I^2t for fusing	125	KA ² s	Sinusoidal half wave, Initial $T_J = T_{J\max}$.
	114		
	88		
	81		
I^2vt Maximum I^2vt for fusing	1250	KA ² /s	$t = 0.1$ to 10ms, no voltage reapplied
$V_{T(TO)1}$ Low level value of threshold voltage	1.08	V	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_{J\max}$.
$V_{T(TO)2}$ High level value of threshold voltage	1.14		$(I > \pi \times I_{T(AV)})$, $T_J = T_{J\max}$.
r_{t1} Low level value of on-state slope resistance	1.18	mΩ	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_{J\max}$.
r_{t2} High level value of on-state slope resistance	1.14		$(I > \pi \times I_{T(AV)})$, $T_J = T_{J\max}$.
V_{TM} Max. on-state voltage	1.96	V	$I_{pk} = 750A$, $T_J = T_{J\max}$, $t_p = 10ms$ sine pulse
I_H Maximum holding current	600	mA	$T_J = T_{J\max}$, anode supply 12V resistive load
I_L Max. (typical) latching current	1000 (300)		

Switching

Parameter	ST180C..C	Units	Conditions
di/dt	Max. non-repetitive rate of rise of turned-on current	1000	A/ μ s
t _d	Typical delay time	1.0	μ s
t _q	Typical turn-off time	100	

Blocking

Parameter	ST180C..C	Units	Conditions
dv/dt	Maximum critical rate of rise of off-state voltage	500	V/ μ s
I _{DRM} I _{RRM}	Max. peak reverse and off-state leakage current	30	mA

Triggering

Parameter	ST180C..C	Units	Conditions
P _{GM}	Maximum peak gate power	10	
P _{G(AV)}	Maximum average gate power	2.0	W
I _{GM}	Max. peak positive gate current	3.0	A
+V _{GM}	Maximum peak positive gate voltage	20	V
-V _{GM}	Maximum peak negative gate voltage	5.0	
I _{GT}	DC gate current required to trigger	TYP. 180 90 40	MAX. - 150 -
V _{GT}	DC gate voltage required to trigger	2.9 1.8 1.2	- 3.0 -
I _{GD}	DC gate current not to trigger	10	mA
V _{GD}	DC gate voltage not to trigger	0.25	V

ST180C..C Series

Bulletin I25164 rev. C 02/00

International
IR Rectifier

Thermal and Mechanical Specification

Parameter	ST180C..C	Units	Conditions
T_J	Max. operating temperature range	-40 to 125	$^{\circ}\text{C}$
T_{stg}	Max. storage temperature range	-40 to 150	
$R_{\text{thJ-hs}}$	Max. thermal resistance, junction to heatsink	0.17	K/W
		0.08	
$R_{\text{thC-hs}}$	Max. thermal resistance, case to heatsink	0.033	K/W
		0.017	
F	Mounting force, $\pm 10\%$	4900 (500)	N (Kg)
wt	Approximate weight	50	g
Case style	TO - 200AB (A-PUK)	See Outline Table	

$\Delta R_{\text{thJ-hs}}$ Conduction

(The following table shows the increment of thermal resistance $R_{\text{thJ-hs}}$ when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.015	0.015	0.011	0.011	K/W	$T_J = T_{J \text{ max.}}$
120°	0.018	0.019	0.019	0.019		
90°	0.024	0.024	0.026	0.026		
60°	0.035	0.035	0.036	0.037		
30°	0.060	0.060	0.060	0.061		

Ordering Information Table

Device Code							
1	-	Thyristor					
2	-	Essential part number					
3	-	0 = Converter grade					
4	-	C = Ceramic Puk					
5	-	Voltage code: Code x 100 = V_{RRM} (See Voltage Rating Table)					
6	-	C = Puk Case TO-200AB (A-PUK)					
7	-	0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads)					
		1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads)					
		2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads)					
		3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)					
8	-	Critical dv/dt: None = 500V/ μsec (Standard value)					
		L = 1000V/ μsec (Special selection)					

Outline Table

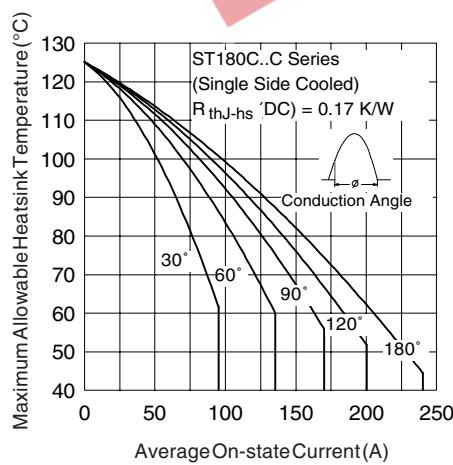
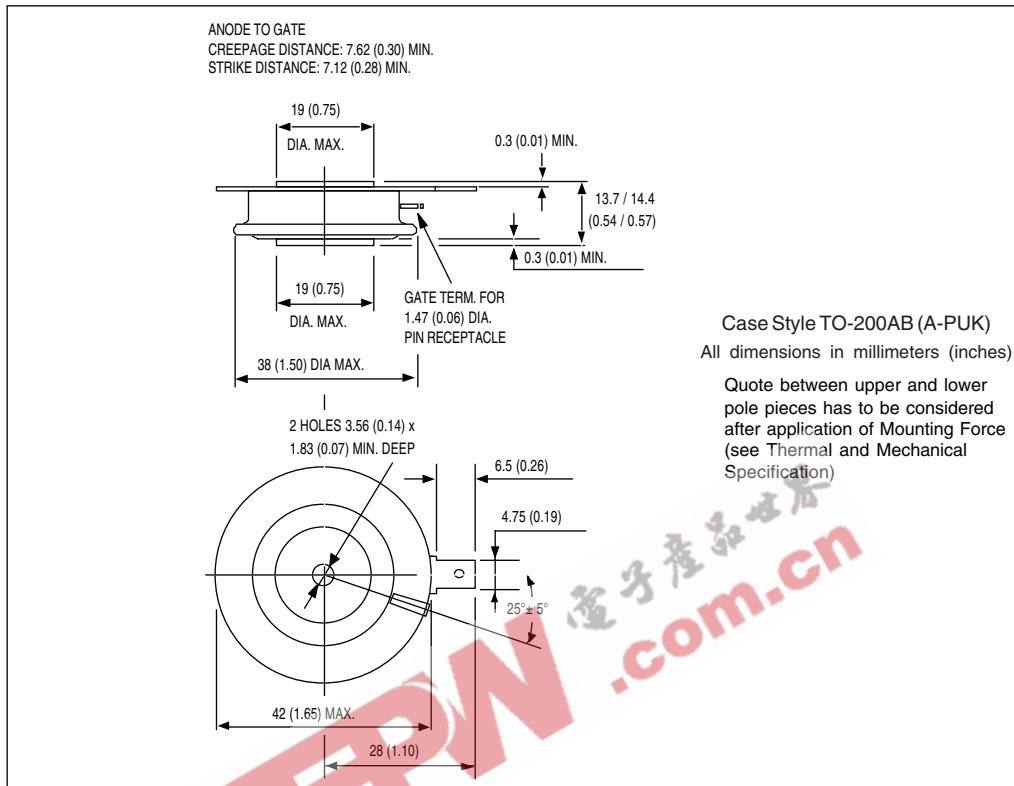


Fig. 1 - Current Ratings Characteristics

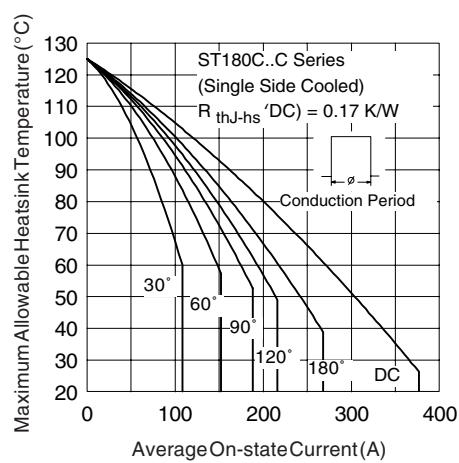


Fig. 2 - Current Ratings Characteristics

ST180C..C Series

Bulletin I25164 rev. C 02/00

International
IR Rectifier

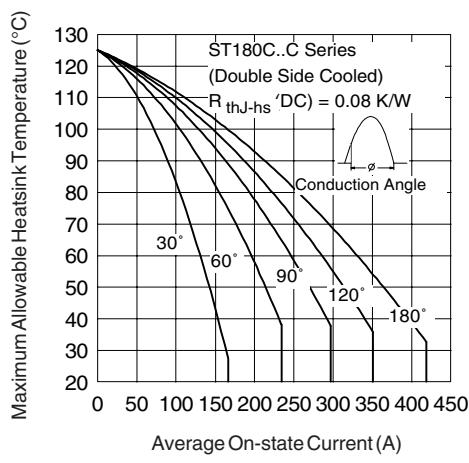


Fig. 3 - Current Ratings Characteristics

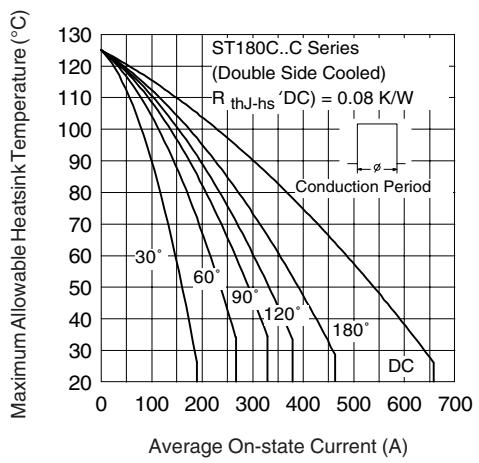


Fig. 4 - Current Ratings Characteristics

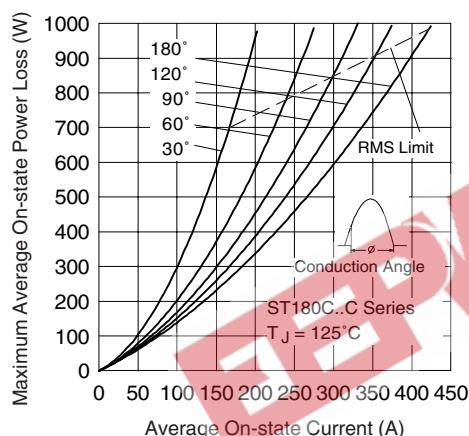


Fig. 5 - On-state Power Loss Characteristics

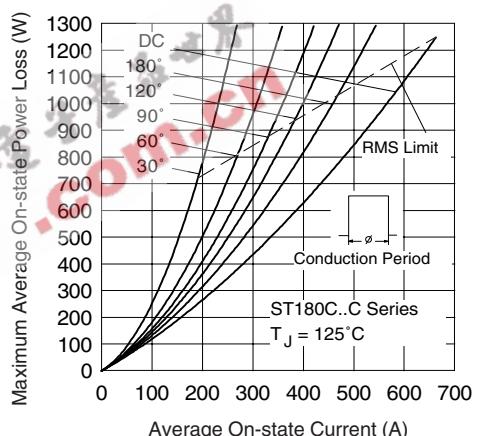


Fig. 6 - On-state Power Loss Characteristics

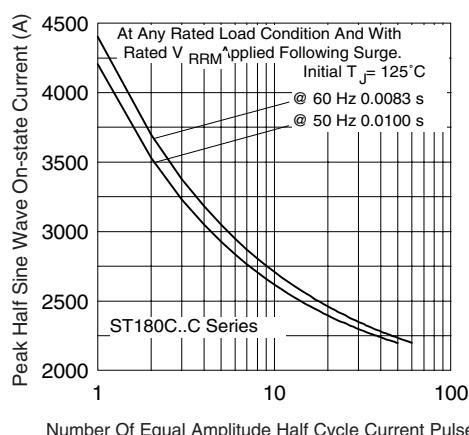


Fig. 7 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

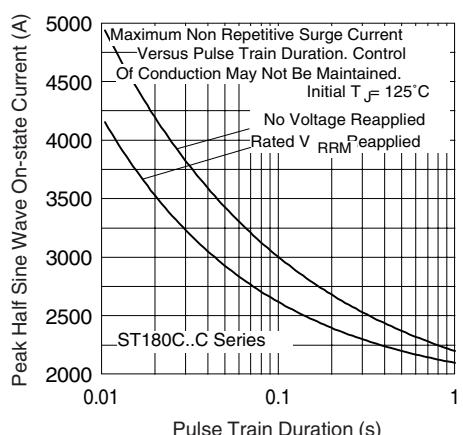


Fig. 8 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

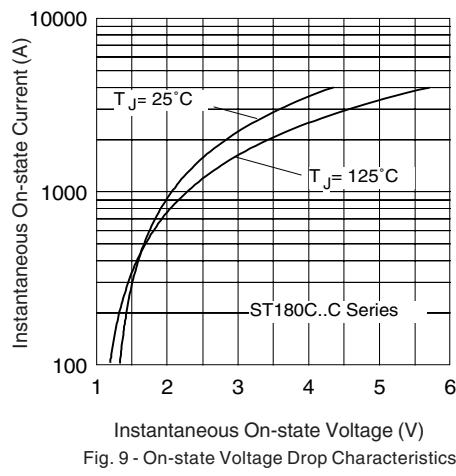


Fig. 9 - On-state Voltage Drop Characteristics

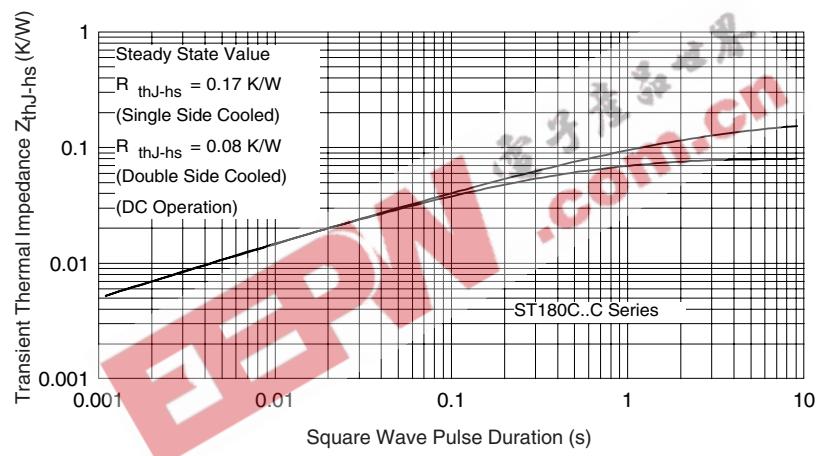


Fig. 10 - Thermal Impedance $Z_{\text{thJ-hs}}$ Characteristics

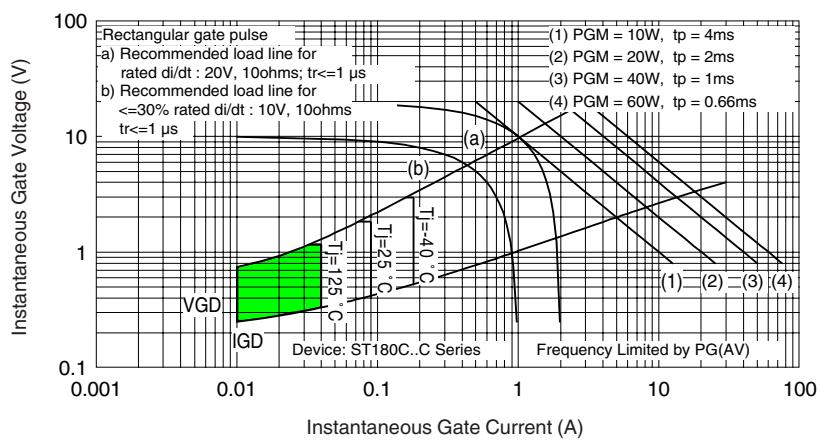


Fig. 11 - Gate Characteristics